ZnO nanoarray based conductometric acetone sensor: a bias and light assisted performance enhancement

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Abstract: In this work, a combination of different bias potentials (0.1 – 9 V) along with 365 nm UV light is applied to enhance the sensing performance of a chemo-resistive device consisting of zinc oxide (ZnO) nanoarrays (NAs) as the sensitive layer for measuring acetone concentrations between 1.2 and 12.5 ppm. To the best of the authors’ knowledge, the application of this double enhancement principle towards chemo-resistive acetone sensors is the first such report in the literature. It was found that an increment in applied bias increased the sensitivity of the device toward acetone. Furthermore, when the sensor was stimulated with a 365 nm UV light source in the presence of 12.5 ppm acetone, the sensitivity was increased by 1.8 times when compared to operating in the dark. The significant sensitivity enhancements are effects of both light and bias, which can be highlighted by the calculated 1 ppb limit of detection (LoD) of the sensor when excited by UV light at 350 °C with a 9 V bias. Additionally the adsorption time (t90-a) and desorption time (t90-d) of the sensor can be greatly improved with bias and light. The t90-a decreased to from 75 s to 9 s and the t90-d from 93 s to 14 s under light for an operating bias of 0.1 and 9 V, respectively.

Key words: Chemo-resistive, ZnO nanoarrays, Acetone sensing, Bias, Light

1. Introduction
Metal oxide semiconductor (MOS) based chemo-resistive sensors are widely studied for acetone sensing due to their high reproducibility, easy fabrication procedures and simple operation. Amongst the metal oxides investigated, ZnO has shown much promise due to its unique optical and semiconducting properties. ZnO NAs morphology is preferred because of its high surface area to volume ratio, single crystalline nature and uniform structures. In addition, ZnO is highly responsive to ultra violet light with the charge carrier generation phenomena at the surface. It is crucial and challenging to attain differentiable sensitivity to identify the different gas concentrations. Therefore, sensors with high gas sensitivity and lower detection limits of < 1 ppm are essential to facilitate applications like the diagnosis of diabetes using exhaled breath. To overcome such issues, this paper investigated the effect of combining both bias and UV light stimulus on a chemo-resistive based acetone sensor to improve its overall performance.

2. Experimental
ZnO was synthesized using a previously reported synthesis method, and morphological analysis was performed using scanning electron microscopy (SEM). The acetone vapor sensing event (acetone exposure) and recovery process (which involved flushing the chamber with dry air) were each set at 5 minutes while maintaining a total flow rate of 200 sccm. The acetone target concentrations were chosen between 1.2 to 12.5 ppm. The acetone sensing performance was tested under operating temperatures ranging from 45 °C to 350 °C with the different potential bias ranging from 0.1 to 9 V DC in a custom built chamber with a quartz window to expose UV light of incident intensity of 2.024 mW·cm-2 for light assisted acetone sensing.

3. Results and discussion
The developed ZnO NAs (Fig. 1a-b) are observed to be uniform in size and vertically oriented with a high density.
The ZnO NAs have a length of approximately 1.2 µm and are 75 nm in diameter. The sensitivity of the sensor toward acetone was observed to increase with increasing bias (see Fig. 1c). This is due to no charge mobility saturation of the semiconductor. The sensitivity increased by 4.5 times more with 9 V bias than 6 V bias as shown in Fig. 1d. The ZnO NAs sensors were highly repeatable (calculated as repeatability (%)) = 100% - CoV (Coefficient of Variance)) with 100% for 9 V bias and more than 97% for other bias values.

**Table 1**: LoD, adsorption time (t90-a) and desorption time (t90-d) for UV assisted acetone sensor under different biases at 350 °C.

<table>
<thead>
<tr>
<th>Bias (V)</th>
<th>LOD (ppm)</th>
<th>(t90-a) (s)</th>
<th>(t90-d) (s)</th>
</tr>
</thead>
<tbody>
<tr>
<td>0.1</td>
<td>0.07</td>
<td>75</td>
<td>93</td>
</tr>
<tr>
<td>3</td>
<td>0.03</td>
<td>30</td>
<td>72</td>
</tr>
<tr>
<td>6</td>
<td>0.006</td>
<td>29</td>
<td>34</td>
</tr>
<tr>
<td>9</td>
<td>0.001</td>
<td>9</td>
<td>14</td>
</tr>
</tbody>
</table>

Further sensitivity of the sensor under light towards acetone was observed to increase with the increasing bias as shown in Fig. 1f. The sensors exhibited almost no memory effect as shown in Fig. 1g.

Interestingly, the combination of bias and light assisted sensing approach introduced in this study has enabled the sensor to operate at 45°C which reduced the efforts of doping or different material synthesis (data to be presented in the full manuscript). The influence of light and bias towards acetone with humidity as a cross-contaminant will also be presented in the final manuscript.

4. Acknowledgments

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5. References

